

DESCRIPTION

The UDN 5711 series of dual peripheral drivers have high voltage (80V) and high current (300mA) NPN output transistors. In addition an overshoot clamp diode is provided for each output collector for use when switching inductive loads.

A choice of AND, NAND, OR and NOR logic functions comprise the four device types in the series.

In use care must be taken to insure that the absolute maximum junction temperature rating is not exceeded due to excessive power dissipation; particularly when switching capacitive or inductive loads at high frequencies.

FEATURES

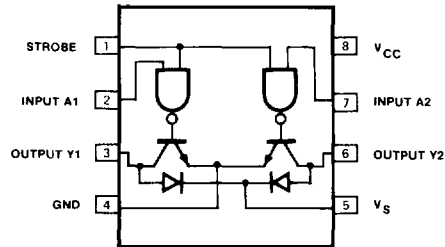
- Four logic functions
- DTL/TTL/PMOS/CMOS compatible inputs
- Low input current loading
- 80V output breakdown

APPLICATIONS

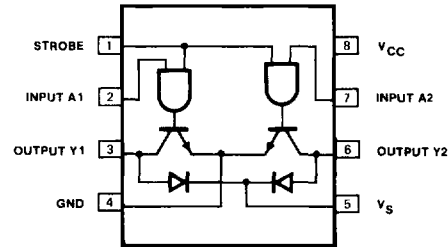
- Relay drivers
- Lamp drivers
- LED drivers
- High current triac trigger

PIN CONFIGURATIONS

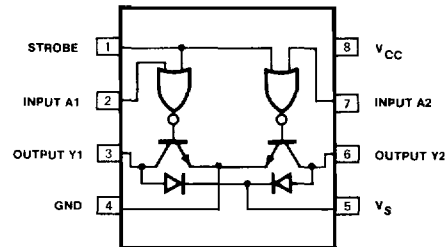
**DUAL AND DRIVER
UDN 5711**



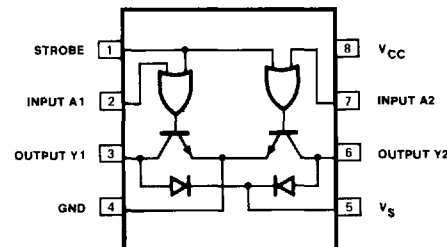
**DUAL NAND DRIVER
UDN 5712**



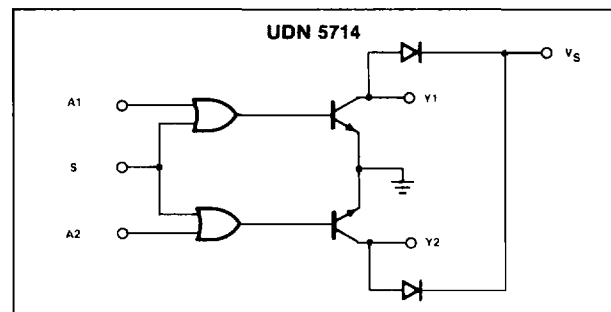
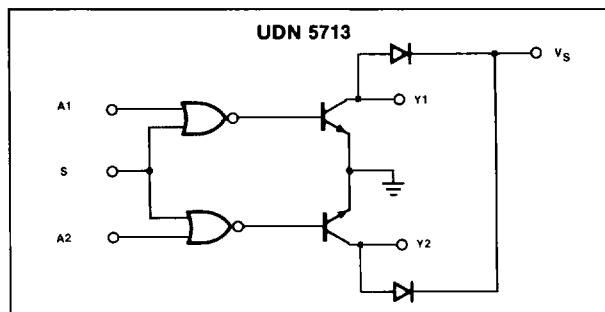
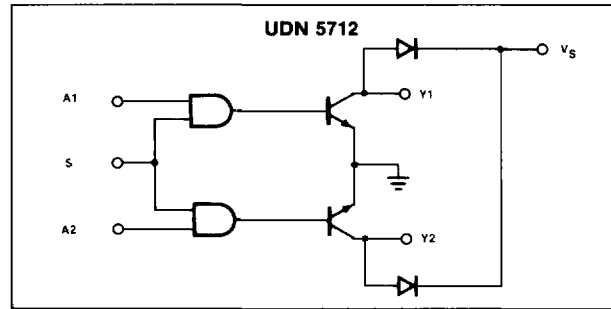
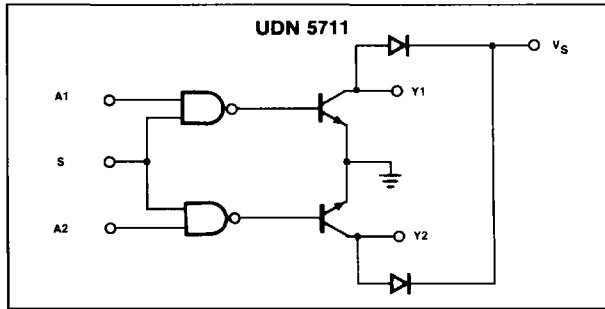
**DUAL OR DRIVER
UDN 5713**



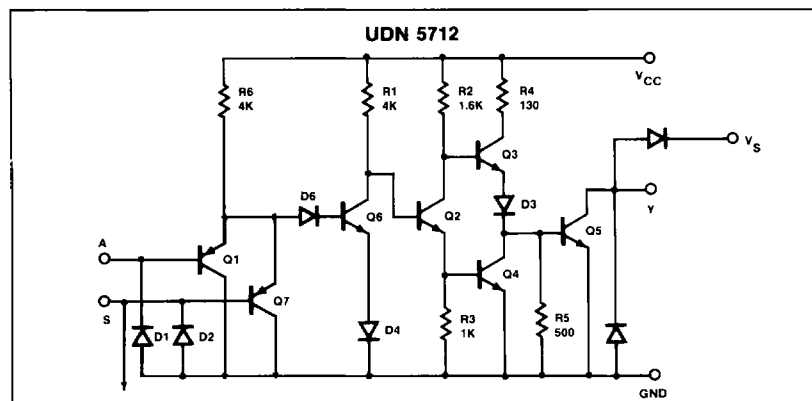
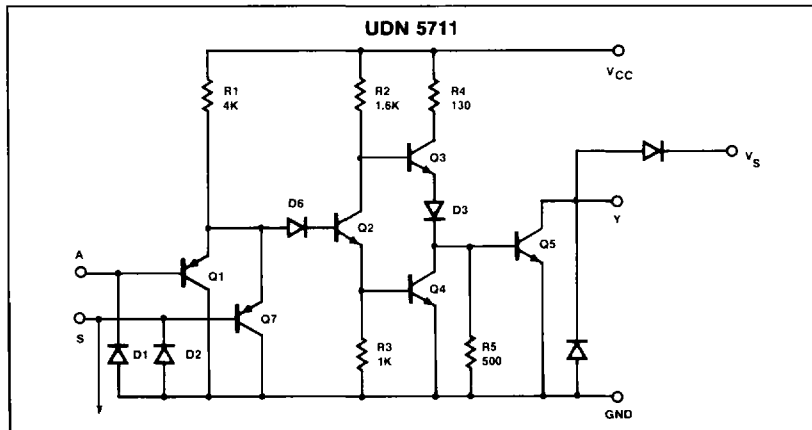
**DUAL NOR DRIVER
UDN 5714**



BLOCK DIAGRAMS

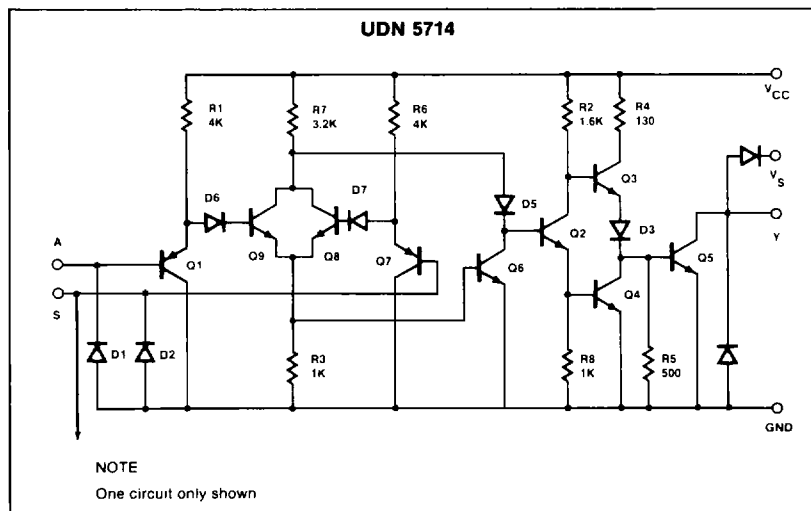
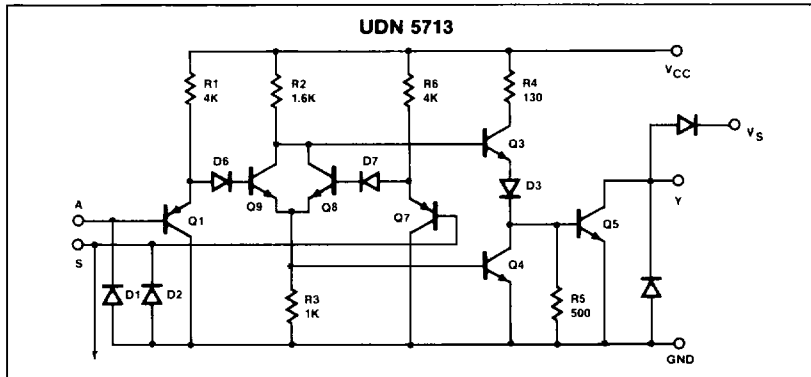


EQUIVALENT CIRCUIT



7

EQUIVALENT CIRCUIT (Cont'd)



ABSOLUTE MAXIMUM RATINGS at 25°C unless otherwise stated.

PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	
	Continuous	7 V
	Momentary (1 second)	15 V
V _{IN}	Input voltage	30 V
V _{OUT}	Output voltage (off state)	80 V
I _{OUT}	Output current	600 mA
V _S	Suppression diode reverse voltage	80 V
I _S	Suppression diode forward current	600 mA
P _D	Power dissipation*	750 mW
T _A	Operating temperature range	0 to 70 °C
T _{stg}	Storage temperature range	-65 to 150 °C
	Lead soldering temperature (10 seconds)	300 °C

NOTE

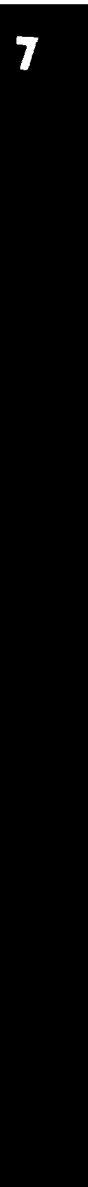
*The maximum junction is 150°C. Derate at 162°C/watt above 25°C.

DC ELECTRICAL CHARACTERISTICS 0°C ≤ T_A ≤ 85°C unless otherwise specified.

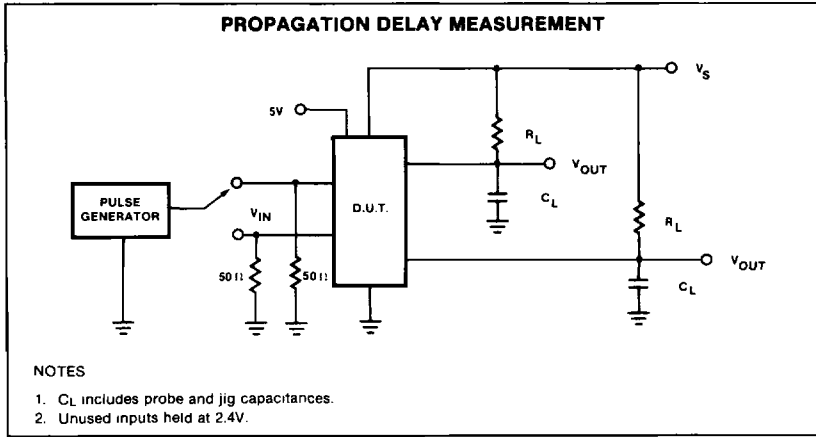
PARAMETER	TEST CONDITIONS	LIMITS			UNIT
		Min	Typ	Max	
V _{CC}	Supply voltage range	4.75	5.00	5.25	V
V _{IH}	Logical "1" input voltage	2.0			V
V _{IL}	Logical "0" input voltage			0.8	V
V _I	Input clamp voltage		-1.2	-1.5	V
I _{IH}	Logical "1" input current except stobe	V _{CC} = 5.25V, V _{IN} = 30V V _{strobe} = 0V	1	10	μA
I _{IH}	Logical "1" input current at stobe	V _{CC} = 5.25V, V _{strobe} = 30V V _{IN} = 0V	2	20	μA
I _{IL}	Logical "0" input current except stobe	V _{CC} = 5.25V, V _{IN} = 0.4V V _{strobe} = 30V	-50	-100	μA
I _{IL}	Logical "0" input current at stobe	V _{CC} = 5.25V, V _{strobe} = 0.4V V _{IN} = 30V	-100	-200	μA
I _{OUT}	Output current	UDN 5711/5713 - V _{IN} = 0.8V UDN 5712/5714 - V _{IN} = 2.0V		300	mA
I _{OH}	Output leakage current	V _{IN} = 2.0V (UDN 5711/5713) V _{IN} = 0.8V (UDN 5712/5714) V _{OH} = 80V, V _{CC} = 5.25V V _{CC} = open		100 100	μA μA
V _{OL}	Output low voltage	V _{IN} = 0.8V (UDN 5711/5713) V _{IN} = 2.0V (UDN 5712/5714) V _{CC} = 4.75V, I _{OL} = 150mA I _{OL} = 300mA	0.35 0.50	0.50 0.70	V V
I _{LD}	Diode leakage current	V _{IN} = 0V (UDN 5711/5713) V _{IN} = 5V (UDN 5712/5714) V _{CC} = 5V, V _{LD} = 80V, T _A = 25°C		200	μA
V _{FD}	Diode forward voltage	I _{FD} = 300mA, T _A = 25°C	1.5	1.75	V
I _{CCH}	Supply current with outputs high	V _{CC} = 5.25V, T _A = 25°C UDN 5711 V _{IN} = 5V UDN 5712 V _{IN} = 0V UDN 5713 V _{IN} = 5V UDN 5714 V _{IN} = 0V	8 12 8 12	12 15 13 15	mA mA mA mA
I _{CCL}	Supply current with outputs low	V _{CC} = 5.25V, T _A = 25°C UDN 5711 V _{IN} = 0V UDN 5712 V _{IN} = 5V UDN 5713 V _{IN} = 0V UDN 5714 V _{IN} = 5V	35 40 36 40	49 53 50 50	mA mA mA mA

AC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITIONS	LIMITS			UNIT
		Min	Typ	Max	
T _{PLH}	Propagation delay time, low-to-high output			500	ns
T _{PHL}	Propagation delay time, high-to-low output			750	ns



TEST LOAD CIRCUITS



VOLTAGE WAVEFORMS

